

BAV13 Diodes

General Purpose Fast Rectifier

Military/High-Rel N

I(O) Max.(A) Output Current 400m

V(RRM)(V) Rep.Pk.Rev. Voltage 50

t(rr) Max.(s) Rev.Rec. Time 10n

@I(F) (A) (Test Condition) 10m

@I(R) (A) (Test Condition) 10m

V(FM) Max.(V) Forward Voltage 1.3

@I(FM) (A) (Test Condition) 400m

@V(RM) (V) (Test Condition)

I(RM) Max.(A) Reverse Current 100n

@V(R) (V)(Test Condition) 35

I(RM) Max.(A) Pk. Rev. Current 150u

@V(R) (V) (Test Condition)

@Temp. (°C) (Test Condition) 150'

Semiconductor Material Silicon

Maximum Operating Temp (°C) 200p

Package Style DO-35